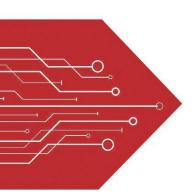
# MSKSEMI















**ESD** 

**TVS** 

**TSS** 

MOV

**GDT** 

**PLED** 

Broduct data speet

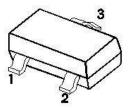
#### **Features**

- PD:225mW
- High Stability and High Reliability
- Low reverse leakage

#### **Mechanical Data**

PKG: SOT-23Epoxy UL: 94V-0

Mounting Position: Any



SOT-23

BAW56-MS	BAV70-MS	BAV99-MS	
10-1	10	10	
20	2 -	20	
MARKING:A1	MARKING:A4	MARKING:A7	
A1	A4	A7	

#### Maximum Ratings & Thermal Characteristics (Ratings at 25℃ ambient temperature unless otherwise specified.)

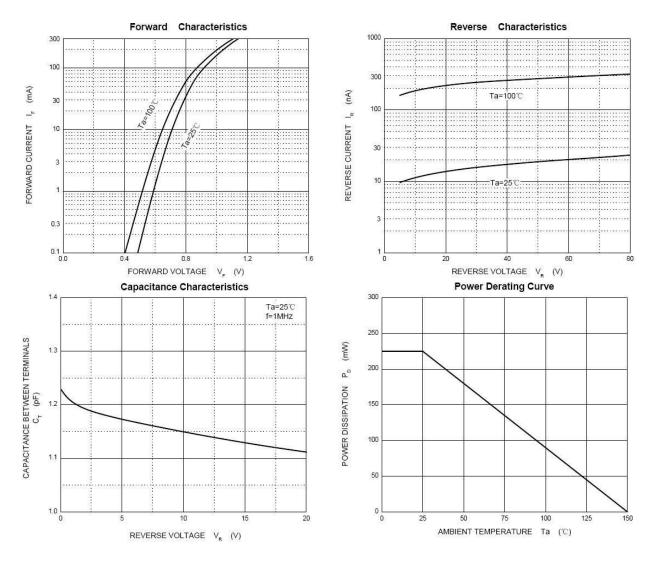
Parameters	Symbol	Value	Unit
Reverse Voltage	VR	70	V
Power Dissipation	Pd	225	mW
Operating junction temperature	Tj	150	$^{\circ}$
Storage temperature range	Ts	-65-+150	$^{\circ}$
Average Rectified Current	lo	200	mA
Non-repetitive Peak Forward Current	IFM	400	mA
Peak Forward Surge Current @tp=1ms; TA=25°C	IFSM	2.0	А
Typical thermal resistance	Reja	500	°C/W

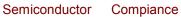
Valid provided that electrodes are kept at ambient temperature.

#### **Electrical Characteristics** (Ratings at 25℃ ambient temperature unless otherwise specified).

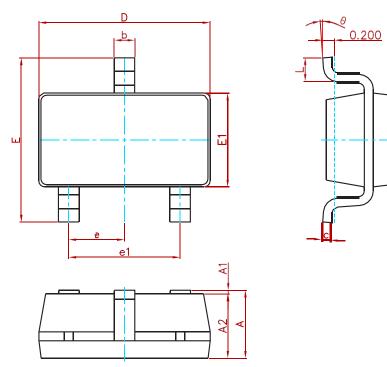
Symbols	Parameter		Limits		T
		Test Condition	Min	Max	Unit
VRB	Reverse Voltage	IB=100uA 70			V
lR	Reverse Leakage Current	VR=70V		2.5	uA
		IF=1mA		0.715	
VF	Forward Voltage	IF=10mA		0.855	V
		IF=50mA		1.00	\ \ \
		IF=150mA		1.25	
TRR	Reverse Recovery Time	IF= IR=10mA,RL=100Ω IRR=0.1xIR 6		nS	
Ст	Capacitance	VR=0V, f=1MHZ		1.5	pF

### **Typical Characteristics**



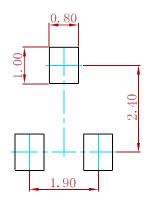


#### **PACKAGE MECHANICAL DATA**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
А	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
е	0.950(	BSC)	0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
0	0°	8°	0°	8°

# **Suggested Pad Layout**



- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

## **REEL SPECIFICATION**

P/N	PKG	QTY
BAW56-MS/BAV70-MS/BAV99-MS	SOT-23	3000



Semiconductor



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